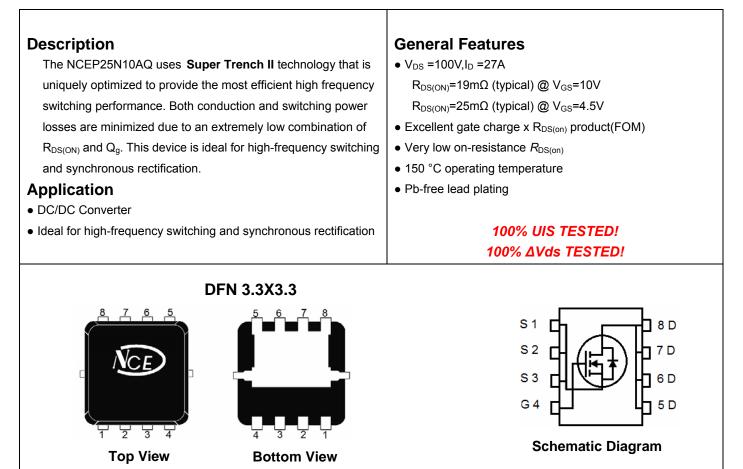


# NCE N-Channel Super Trench II Power MOSFET



## Package Marking and Ordering Information

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
NCEP25N10AQ	NCEP25N10AQ	DFN3.3X3.3-8L	-	-	-

## Absolute Maximum Ratings (T<sub>c</sub>=25<sup>°</sup>C unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	Vds	100	V
Gate-Source Voltage	Vgs	±20	V
Drain Current-Continuous	I <sub>D</sub>	27	А
Drain Current-Continuous(T <sub>C</sub> =100℃)	I <sub>D</sub> (100℃)	19	A
Pulsed Drain Current	I <sub>DM</sub>	108	A
Maximum Power Dissipation	PD	38	W
Derating factor		0.31	W/℃
Single pulse avalanche energy (Note 5)	E <sub>AS</sub>	97	mJ
Operating Junction and Storage Temperature Range	T <sub>J</sub> ,T <sub>STG</sub>	-55 To 150	°C

## **Thermal Characteristic**

Thermal Resistance, Junction-to-Case <sup>(Note 2)</sup>	R <sub>θJC</sub>	3.29	°C/W
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# Electrical Characteristics (T<sub>c</sub>=25<sup>°</sup>C unless otherwise noted)

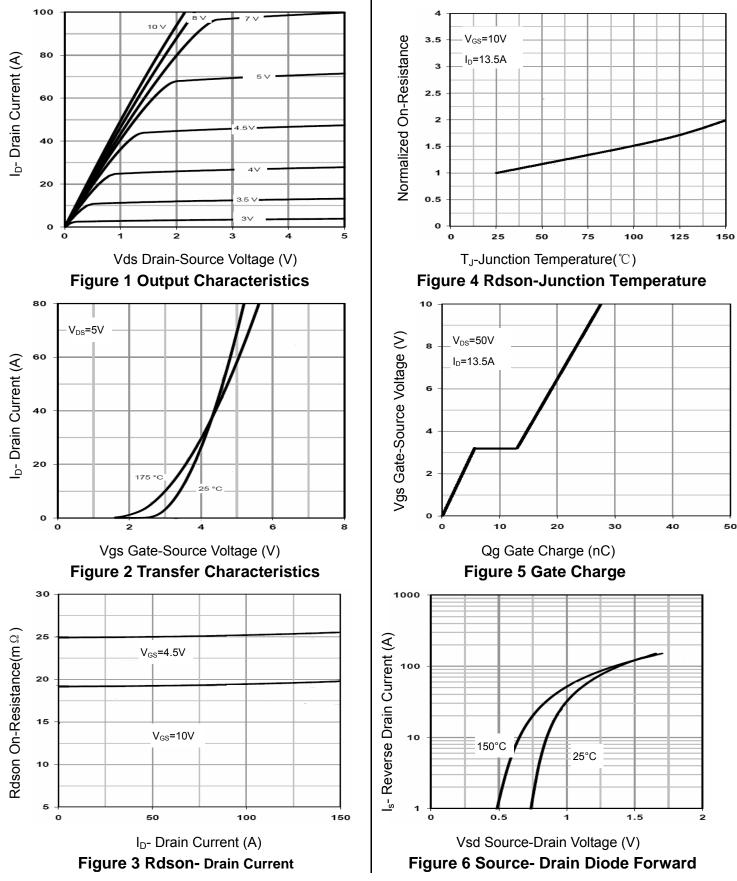
$V_{GS}=0V I_{D}=250\mu A$ $V_{DS}=100V, V_{GS}=0V$ $V_{GS}=\pm 20V, V_{DS}=0V$ $V_{DS}=V_{GS}, I_{D}=250\mu A$ $V_{GS}=10V, I_{D}=13.5A$ $V_{GS}=4.5V, I_{D}=13.5A$	100 - - 1.1	Typ - -	- 1 ±100	V µA nA
$V_{DS}=100V, V_{GS}=0V$ $V_{GS}=\pm 20V, V_{DS}=0V$ $V_{DS}=V_{GS}, I_{D}=250\mu A$ $V_{GS}=10V, I_{D}=13.5A$ $V_{GS}=4.5V, I_{D}=13.5A$	- - 1.1	-	1	μA
V <sub>GS</sub> =±20V,V <sub>DS</sub> =0V V <sub>DS</sub> =V <sub>GS</sub> ,I <sub>D</sub> =250µA V <sub>GS</sub> =10V, I <sub>D</sub> =13.5A V <sub>GS</sub> =4.5V, I <sub>D</sub> =13.5A	-	-		
$V_{DS}=V_{GS}, I_D=250\mu A$ $V_{GS}=10V, I_D=13.5A$ $V_{GS}=4.5V, I_D=13.5A$	1.1		±100	nA
V <sub>GS</sub> =10V, I <sub>D</sub> =13.5A V <sub>GS</sub> =4.5V, I <sub>D</sub> =13.5A	-	4 7		
V <sub>GS</sub> =10V, I <sub>D</sub> =13.5A V <sub>GS</sub> =4.5V, I <sub>D</sub> =13.5A	-	4 7		
V <sub>GS</sub> =4.5V, I <sub>D</sub> =13.5A	_	1.7	2.5	V
	-	19	25	mΩ
	-	25	30	mΩ
$V_{DS}$ =5V,I <sub>D</sub> =13.5A	-	19	-	S
	-	1317.6	-	PF
	-	123.9	-	PF
	-	19.3	-	PF
	-	13	-	nS
V <sub>DD</sub> =50V,I <sub>D</sub> =13.5A	-	15	-	nS
$V_{GS}$ =10V, $R_{G}$ =3 $\Omega$	-	22	-	nS
	-	6	-	nS
	-	27.6	-	nC
	-	5.5		nC
V <sub>GS</sub> =10V	-	6.9		nC
		· ·	<b>!</b>	
V <sub>GS</sub> =0V,I <sub>S</sub> =13.5A	-		1.2	V
	-	-	27	А
T. = 25°C I_ = 13.5A	-	40	_	nS
$I_{\rm J} = 200, I_{\rm F} = 10.0$ A			l	
	$V_{GS}$ =10V,R <sub>G</sub> =3 $\Omega$ $V_{DS}$ =50V,I <sub>D</sub> =14A, $V_{GS}$ =10V	$\begin{array}{c c} F=1.0 \text{MHz} & - & \\ \hline & & \\ \hline & & \\ V_{DD}=50 \text{V}, \text{I}_D=13.5 \text{A} & - \\ \hline & & \\ V_{GS}=10 \text{V}, \text{R}_G=3 \Omega & - \\ \hline & & \\ \hline & & \\ V_{DS}=50 \text{V}, \text{I}_D=14 \text{A}, & \\ \hline & & \\ V_{GS}=10 \text{V} & - \\ \hline & & \\ \hline & & \\ \hline & & \\ V_{GS}=0 \text{V}, \text{I}_S=13.5 \text{A} & - \\ \hline & & \\ \hline \end{array}$	$\begin{array}{c c c c c c c c c c c c c c c c c c c $	$\begin{array}{c c c c c c c c c c c c c c c c c c c $

#### Notes:

- 1. Repetitive Rating: Pulse width limited by maximum junction temperature.
- 2. Surface Mounted on FR4 Board,  $t \le 10$  sec.
- 3. Pulse Test: Pulse Width ≤ 300 $\mu$ s, Duty Cycle ≤ 2%.
- 4. Guaranteed by design, not subject to production 5. EAS condition : Tj=25 $^\circ\!\!C,V_{DD}$ =50V,V\_G=10V,L=0.5mH,Rg=25 $\Omega$



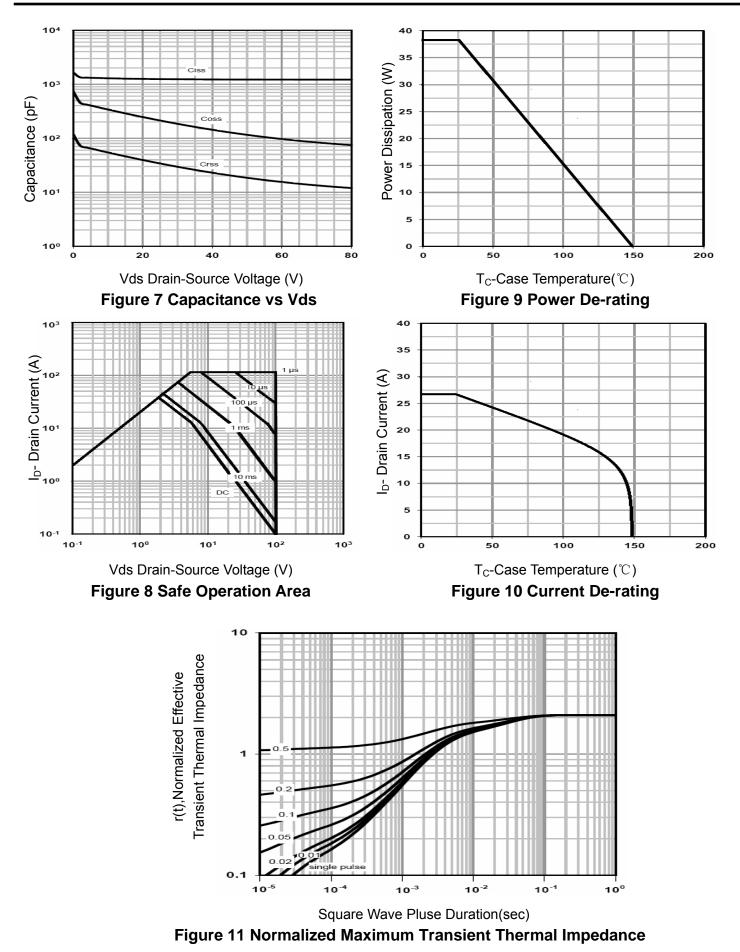
# **Typical Electrical and Thermal Characteristics**





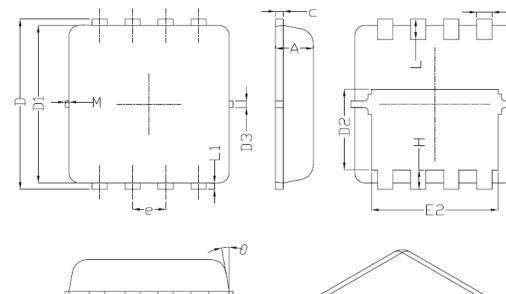
http://www.ncepower.com

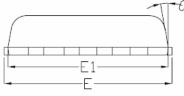
# NCEP25N10AQ

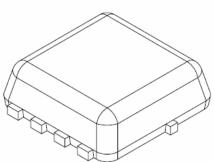




# DFN3.3X3.3-8L Package Information







Symbol	Dimensions In Millimeters			
Symbol	Min.	Nom.	Max.	
A	0.70	0.75	0.80	
b	0.25	0.30	0.35	
с	0.10	0.15	0.25	
D	3.25	3.35	3.45	
D1	3.00	3.10	3.20	
D2	1.48	1.58	1.68	
D3	-	0.13	-	
E	3.20	3.30	3.40	
E1	3.00	3.15	3.20	
E2	2.39	2.49	2.59	
e	0.65BSC			
Н	0.30	0.39	0.50	
L	0.30	0.40	0.50	
L1	-	0.13	-	
М	*	*	0.15	
θ		10 <sup>°</sup>	12 <sup>°</sup>	



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